

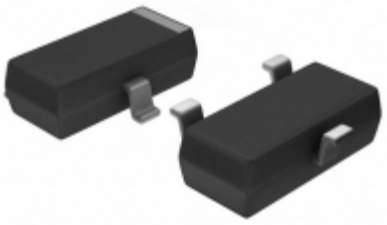


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|---|---|
|  | <p><b>SI2392DS-T1-GE3</b></p>   |
|   | <p><b>Hersteller-Teilenummer:</b> SI2392DS-T1-GE3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 3.1A SOT-23</p> <p><b>Datenblätter:</b>  SI2392DS-T1-GE3.pdf</p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 66816 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
|  |   |
| <p>Image may be representation.<br/>See specs for product details.</p>            |   |

Spezifikationen

|  |  |
|--|--|
| Teilenummer                                      | SI2392DS-T1-GE3                                  |
| Hersteller                                       | Vishay / Siliconix                               |
| Beschreibung                                     | MOSFET N-CH 100V 3.1A SOT-23                     |
| Kategorie  | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus                                       | 66816 pcs Stock                                  |
| Serie  | TrenchFET®                                       |
| Technologie                                      | MOSFET (Metal Oxide)                             |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)                               |
| Befestigungsart                                  | Surface Mount                                    |
| Verpackung / Gehäuse                             | TO-236-3, SC-59, SOT-23-3                        |
| Supplier Device-Gehäuse                          | SOT-23   |
| Verlustleistung (max)                            | 1.25W (Ta), 2.5W (Tc)                            |
| Typ FET  | N-Channel  |
| FET-Merkmal                                      | -  |
| Drain-Source-Spannung (Vdss)                     | 100V   |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 3.1A (Tc)  |
| Rds On (Max) @ Id, Vgs                           | 126 mOhm @ 2A, 10V                               |
| VGS (th) (Max) @ Id                              | 3V @ 250µA                                       |
| Gate Charge (Qg) (Max) @ Vgs                     | 10.4nC @ 10V                                     |
| Eingabekapazität (Ciss) (Max) @ Vds              | 196pF @ 50V                                      |
| Verpackung                                       | Tape & Reel (TR)                                 |





























SI2392DS-T1-GE3 ist neu im Original, Suche SI2392DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2392DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2392DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

|   |   |  |  |
|---|---|--|--|
|  <p><b>SI2392DS-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 100V 3.1A SOT-23</p> |  <p><b>SI2399</b><br/>SIPU<br/>SI2399 SIPU</p>   |  <p><b>SI2392ADS-T1-E3</b><br/>VISHAY<br/>SI2392ADS-T1-E3 VISHAY</p> |  <p><b>SI2392ADS-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 100V 3.1A SOT-23</p> |
|  <p><b>SI2399DS-T1-E3</b><br/>Son<br/>SI2399DS-T1-E3 Son</p>                                     |  <p><b>SI2377EDS-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 20V 4.4A SOT-23</p> |  <p><b>SI2399CDS-T1-GE3</b><br/>V<br/>SI2399CDS-T1-GE3 V</p>         |  <p><b>SI2399DS-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 20V 6A SOT-23</p>     |

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|--|---|--|---|--|
|  SI2366DS-T1-E3   |  SI2366DS-T1-GE  |  SI2366DS-T1-GE3  |  SI2366DS-T1-GE3  |  SI2367DS-T1-E3   |
|  SI2367DS-T1-GE3  |  SI2367DS-T1-GE3 |  SI2369DS-T1-GE3  |  SI2369DS-T1-GE3  |  SI2371EDS-T1-GE3 |
|  SI2371EDS-T1-GE3 |  SI2372DS-T1-E3  |  SI2372DS-T1-GE3  |  SI2372DS-T1-GE3  |  SI2374DS-T1-GE3  |
|  SI2374DS-T1-GE3  |  SI2377DS-T1-GE3 |  SI2377EDS        |  SI2377EDS-T1-E3  |  SI2377EDS-T1-GE3 |
|  SI2377EDS-T1-GE3 |  SI2392ADS-T1-E3 |  SI2392ADS-T1-GE3 |  SI2392ADS-T1-GE3 |  SI2392DS-T1-GE3  |
|  SI2399CDS-T1-GE3 |  SI2399DS-T1-GE3 |  SI2399DS-T1-GE3  |  SI2400-BS        |  SI2400-FS        |
|  SI2400-FSR       |  SI2400-KS       |  SI2400-KSR       |  SI2401-FS        |  SI2401-FSR       |
|  SI2401-FSR       |  SI2401-KS       |  SI2403-FTR       |  SI2404-C-FSR     |  SI2404-C-FTR     |
|  SI2404-C-ZSR     |  SI2404-CFTRP    |  SI2404-FS        |  SI2404-FT        |  SI2413AP         |
|  SI2414-F-FTR     |  SI2414-FT       |  SI2414-FTR       |  SI2414-KT        |  SI2415-C-FT      |

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